**IRHSNA57064 / IRHSLNA57064 - Sync Rectifier N-Channel MOSFET**

**Changes to Electrical Characteristics @ Tj = 25°C:**

IDSS Zero Gate Voltage Drain Current, with VDS = 48V, VGS=0V

From 0.050mA to 0.090mA

**Reason for Change:**

Increase reverse leakage current maximum limit to provide better statistical margins based on device capability.

Datasheet Reference: PD-94401 and PD-94323